## HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

- HIGH VOLTAGE CAPABILITY
- LOW SPREAD OF DYNAMIC PARAMETERS
- MINIMUM LOT-TO-LOT SPREAD FOR RELIABLE OPERATION
- VERY HIGH SWITCHING SPEED


## APPLICATIONS

- ELECTRONIC BALLASTS FOR

FLUORESCENT LIGHTING (277 V HALF BRIDGE AND 120 V PUSH-PULL TOPOLOGIES)

DESCRIPTION
The BUL1203E is a new device manufactured using Diffused Collector technology to enhance switching speeds and tight $h_{F E}$ range while maintaining a wide RBSOA.
Thanks to his structure it has an intrinsic ruggedness which enables the transistor to withstand a high collector current level during Breakdown condition, without using the transil protection usually necessary in typical converters for lamp ballast.


INTERNAL SCHEMATIC DIAGRAM


## ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{CBO}}$ | Collector-BaseVoltage $\left(\mathrm{I}_{\mathrm{E}}=0\right)$ | 1200 | V |
| $\mathrm{~V}_{\mathrm{CES}}$ | Collector-Emitter Voltage $\left(\mathrm{V}_{\mathrm{BE}}=0\right)$ | 1200 | V |
| $\mathrm{~V}_{\mathrm{CEO}}$ | Collector-Emitter Voltage $\left(\mathrm{I}_{\mathrm{B}}=0\right)$ | 550 | V |
| $\mathrm{~V}_{\text {EBO }}$ | Emitter-Base Voltage $\left(\mathrm{I}_{\mathrm{C}}=0\right)$ | 9 | V |
| $\mathrm{I}_{\mathrm{C}}$ | Collector Current | 5 | A |
| $\mathrm{I}_{\mathrm{CM}}$ | Collector Peak Current $\left(\mathrm{t}_{\mathrm{p}}<5 \mathrm{~ms}\right)$ | 8 | A |
| $\mathrm{I}_{\mathrm{B}}$ | Base Current | 2 | A |
| $\mathrm{I}_{\mathrm{BM}}$ | Base Peak Current $\left(\mathrm{t}_{\mathrm{p}}<5 \mathrm{~ms}\right)$ | 4 | A |
| $\mathrm{P}_{\text {tot }}$ | Total Dissipation at $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 100 | W |
| $\mathrm{~T}_{\text {stg }}$ | Storage Temperature | -65 to 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{j}}$ | Max. Operating Junction Temperature | 150 | ${ }^{\circ} \mathrm{C}$ |

## THERMAL DATA

| $\mathrm{R}_{\text {thj-case }}$ | Thermal Resistance Junction-case | Max | 1.25 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| :--- | :--- | :--- | :--- | :--- |

ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\text {case }}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Symbol | Parameter | Test Conditions |  | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Ices | Collector Cut-off Current (VBE $=0$ ) | $\mathrm{V}_{\text {CE }}=1200 \mathrm{~V}$ |  |  |  | 100 | $\mu \mathrm{A}$ |
| Iceo | Collector Cut-off <br> Current ( $\mathrm{I}_{\mathrm{B}}=0$ ) | $\mathrm{V}_{\mathrm{CE}}=550 \mathrm{~V}$ |  |  |  | 100 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {CEO }}$ (sus)* | Collector-Emitter Sustaining Voltage ( $\mathrm{I}_{\mathrm{B}}=0$ ) | $\mathrm{I}_{\mathrm{C}}=100 \mathrm{~mA}$ | $\mathrm{L}=25 \mathrm{mH}$ | 550 |  |  | V |
| Vebo | Emitter-Base Voltage $\left(I_{C}=0\right)$ | $\mathrm{IE}_{\mathrm{E}}=10 \mathrm{~mA}$ |  | 9 |  |  | V |
| $V_{\text {CE(sat)* }}$ | Collector-Emitter Saturation Voltage | $\begin{aligned} & \mathrm{IC}=1 \mathrm{~A} \\ & \mathrm{IC}=2 \mathrm{~A} \\ & \mathrm{IC}=3 \mathrm{~A} \end{aligned}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{B}}=0.2 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{B}}=0.4 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{B}}=1 \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 0.7 \\ & 1.5 \end{aligned}$ | $\begin{aligned} & V \\ & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\mathrm{BE}(\mathrm{sat})}{ }^{*}$ | Base-Emitter <br> Saturation Voltage | $\begin{aligned} & \mathrm{IC}=2 \mathrm{~A} \\ & \mathrm{IC}=3 \mathrm{~A} \end{aligned}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{B}}=0.4 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{B}}=1 \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 1.5 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{h}_{\text {FE* }}$ | DC Current Gain | $\begin{aligned} & \mathrm{I} \mathrm{C}=1 \mathrm{~mA} \\ & \mathrm{I}=10 \mathrm{~mA} \\ & \mathrm{I}=0.8 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{C}}=2 \mathrm{~A} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CE}}=3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} \hline 10 \\ 10 \\ 14 \\ 9 \end{gathered}$ |  | $\begin{aligned} & 32 \\ & 28 \end{aligned}$ |  |
| $\begin{gathered} \mathrm{t}_{\mathrm{on}} \\ \mathrm{t}_{\mathrm{s}} \\ \mathrm{tff}^{\text {a }} \end{gathered}$ | RESISTIVE LOAD <br> Turn-on Time Storage Time Fall Time | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=2 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{B} 2}=-0.8 \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=150 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{B} 1}=0.4 \mathrm{~A} \\ & \mathrm{tp}=30 \mu \mathrm{~s} \\ & \text { (see figure 2) } \end{aligned}$ |  | $\begin{aligned} & 2.5 \\ & 0.2 \end{aligned}$ | $\begin{aligned} & 0.5 \\ & 3.0 \\ & 0.3 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{s} \\ & \mu \mathrm{~s} \\ & \mu \mathrm{~s} \end{aligned}$ |
| $\mathrm{Ear}_{\text {a }}$ | Repetitive Avalanche Energy | $\begin{aligned} & \mathrm{L}=2 \mathrm{mH} \\ & \mathrm{~V}_{\mathrm{CC}}=50 \mathrm{~V} \\ & \text { (see figure 3) } \end{aligned}$ | $\begin{aligned} & C=1.8 \mathrm{nF} \\ & \mathrm{~V}_{\mathrm{BE}}=-5 \mathrm{~V} \end{aligned}$ | 6 |  |  | mJ |

* Pulsed: Pulse duration = $300 \mu \mathrm{~s}$, duty cycle $1.5 \%$


## Safe Operating Area



Derating Curve


DC Current Gain


Collector-Emitter Saturation Voltage


Inductive Load Storage Time


DC Current Gain


Base-Emitter Saturation Voltage


Inductive Load Fall Time

| I |
| :--- |

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Reverse Biased Safe Operating Area


Figure 1: Inductive Load Switching Test Circuit


Figure 2: Resistive Load Switching Test Circuit


Figure 3: Energy Rating Test Circuit


BUL1203E

| TO-220 MECHANICAL DATA |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DIM. | mm |  |  | inch |  |  |
|  | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 4.40 |  | 4.60 | 0.173 |  | 0.181 |
| C | 1.23 |  | 1.32 | 0.048 |  | 0.052 |
| D | 2.40 |  | 2.72 | 0.094 |  | 0.107 |
| E | 0.49 |  | 0.70 | 0.019 |  | 0.027 |
| F | 0.61 |  | 0.88 | 0.024 |  | 0.034 |
| F1 | 1.14 |  | 1.70 | 0.044 |  | 0.067 |
| F2 | 1.14 |  | 1.70 | 0.044 |  | 0.067 |
| G | 4.95 |  | 5.15 | 0.194 |  | 0.202 |
| G1 | 2.40 |  | 2.70 | 0.094 |  | 0.106 |
| H2 | 10.00 |  | 10.40 | 0.394 |  | 0.409 |
| L2 |  | 16.40 |  |  | 0.645 |  |
| L4 | 13.00 |  | 14.00 | 0.511 |  | 0.551 |
| L5 | 2.65 |  | 2.95 | 0.104 |  | 0.116 |
| L6 | 15.25 |  | 15.75 | 0.600 |  | 0.620 |
| L7 | 6.20 |  | 6.60 | 0.244 |  | 0.260 |
| L9 | 3.50 |  | 3.93 | 0.137 |  | 0.154 |
| M |  | 2.60 |  |  | 0.102 |  |
| DIA. | 3.75 |  | 3.85 | 0.147 |  | 0.151 |



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